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Cold sintered, temperature-stable $\text{CaSnSiO}_5\text{-K}_2\text{MoO}_4$ composite microwave ceramics and its prototype microstrip patch antenna

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ABSTRACT

Dense $(1-x)\text{wt}\%\text{CaSnSiO}_5\text{-}x\text{wt}\%\text{K}_2\text{MoO}_4$ (CSSO-KMO) composite ceramics were fabricated by the cold sintering process at 180 °C under 400 MPa for 60 min. X-ray diffraction, Energy dispersive X-ray and Raman spectroscopy confirmed that CSSO and KMO coexisted without intermediate phases. As KMO weight fraction increased, relative permittivity (ϵ_r) and temperature coefficient of resonant frequency (τ_f) decreased and the microwave quality factor ($Q \times f$, where f is resonant frequency) increased. Near-zero τ_f (-0.5 ppm/°C) was obtained for 65wt%CSSO-35wt%KMO with $\epsilon_r \sim 9.2$ and $Q \times f \sim 6240$ GHz. No chemical reaction between ceramic composites and silver was observed, demonstrating potential for cofiring with Ag-paste. A prototype antenna was fabricated from 65wt%CSSO-35wt%KMO composite ceramic with a bandwidth of 144 MHz @ -10 dB, a gain of 5.7 dBi and a total efficiency of 88.4% at 5.2 GHz, suitable for 5G mobile communication systems.

Keywords: microwave dielectric, cold sintering process, microstrip patch antenna

INTRODUCTION

Microwave dielectric ceramics are commonly used in communication systems in components such as antennas, duplexers, resonators and substrates^[1,2]. With the development fifth-generation technology for cellular networks (5G), faster and more reliable broadband access is required with larger capacity and shorter transmission response time (delay less than 1ms). To reduce the signal delay of the system, it is necessary to optimize the signal transmission response mode, system structure and physical hardware. The propagation speed of electromagnetic waves is inversely proportional to the relative permittivity (ϵ_r) and low ϵ_r values minimize the cross-coupling between air and dielectrics for 5G applications. At the same time, high microwave quality factor ($Q \times f$, where f is the resonant frequency) improves selectivity and energy transmission, and near zero temperature coefficient of resonant frequency (τ_f) maintains temperature stability of components in operation^[3-10]. Temperature-stable silicates such as $\text{Ca}_2\text{Al}_2\text{SiO}_7$ ^[11], $\text{Y}_3\text{MgAl}_3\text{SiO}_{12}$ ^[12], Mg_2SiO_4 ^[13] and $(\text{Sr},\text{Ba})\text{Y}_2\text{Si}_3\text{O}_{10}$ ^[14] with low ϵ_r (4~15) and high $Q \times f$ (20000~240000 GHz) have therefore, attracted attention as candidates for 5G applications. However, silicate-based ceramics are conventionally sintered at high temperatures ($> 1200^\circ\text{C}$), consuming energy and releasing carbon. The cold sintering process (CSP) can densify ceramics and composites at ultralow temperatures ($< 200^\circ\text{C}$), temperatures that not only reduce carbon emissions but also facilitate direct deposition onto printed circuit boards^[15-27].

CaSnSiO_5 (CSSO) is conventionally sintered at 1450°C with $\epsilon_r \sim 10.9$, $\tau_f \sim 35 \text{ ppm}/^\circ\text{C}$, $Q \times f \sim 43600 \text{ GHz}$ ^[28,29] and is therefore, an ideal base to begin the search for cold sintered silicates. However, initial cold sintering studies of CSSO were unsuccessful and hence, following work by Wang and co-workers^[26,27], K_2MoO_4 (KMO) was used as a fluxing agent to encourage densification and to tune τ_f to near zero. The microstructure, Ag compatibility and microwave dielectric properties of CSSO-KMO composites were therefore, investigated followed by the design, fabrication and testing of a prototype microstrip patch antenna on substrates made from optimum compositions.

EXPERIMENTAL SECTION

(1-x)wt%CSSO-xwt%KMO ($x = 20, 30, 35, 40, 50, 60, 70, 80, 90$ and 100) composite ceramics were prepared by CSP. CSSO powder was synthesized by a traditional high-temperature solid-state method. The raw materials, CaCO_3 (Acros Organics, 99.99%), SiO_2 (Acros Organics, 99.99%) and SnO_2 (Acros Organics, 99.99%) were weighed according to the stoichiometric ratio of CaCO_3 : SiO_2 : $\text{SnO}_2 = 1:1:1$, and then planetary ball-milled 4 hours in isopropanol. The mixed powders were dried and calcined at $1450\text{ }^\circ\text{C}$ for 4 hours to synthesize the CSSO powders. To obtain fine and uniform CSSO powders, the calcined CSSO powders were re-milled 4 hours, dried, and then sieved using a $48\text{ }\mu\text{m}$ Nylon screen. CSSO and KMO (Alfa Aesar, $> 99\%$) powders were weighed and mixed with $\sim 15\%$ deionized water. CSSO-KMO composite ceramics were obtained by hot-pressing mixed powders in a 12 mm die at $180\text{ }^\circ\text{C}$ for 60 min under a uniaxial pressure of 400 MPa, after which samples were placed in an oven at $120\text{ }^\circ\text{C}$ for 24 hours to remove residual moisture. Furthermore, in order to reveal the chemical compatibility, a Heraeus LTC3602 low temperature Ag paste was printed between two green pellets, and then cofired by cold sintering to form a sandwich structure.

The geometric method was used to calculate the bulk density of composite ceramics [30-32]. X-ray powder diffraction (XRD, D2 Phaser, Bruker) using $\text{CuK}\alpha$ radiation was employed to identify crystal structure and phase composition. Scanning electron microscope (SEM, Inspect F50, FEI) equipped with energy dispersive spectroscopy (EDS) was used to examine the microstructure on the polished surface and cross section of composite ceramics. Raman spectra were collected at room temperature using a Raman spectrometer (LabRAM HR800) excited with an Ar^+ laser (514.5 nm). Temperature and frequency dependence of ϵ_r was measured using an Agilent 4294A impedance analyzer from room temperature to $250\text{ }^\circ\text{C}$. Impedance spectroscopy was performed using an Agilent E4980A impedance AC analyzer from 20 to 10^6 Hz . A vector network analyzer (R3767CH, Advantest Corporation, Tokyo, Japan) was measured the microwave properties of the composite ceramics by the TE_{018} dielectric resonator method. The cavity was heated by Peltier device and the resonance

frequency (f) was measured in the range from 25 to 85 °C. The following formula was used to obtain the corresponding τ_f value:

$$\tau_f = \frac{f_T - f_{T_0}}{f_{T_0} \times (T_T - T_{T_0})} \times 10^6 (\text{ppm}/^\circ\text{C}) \quad (1)$$

where f_{T_0} and f_T represent f at T_0 (25 °C) and T (85 °C), respectively.

RESULTS AND DISCUSSION

Fig. 1 shows the XRD patterns of synthesized CSSO powder, KMO raw powder and cold-sintered CSSO-KMO composites. Both CSSO (space group $A2/a$, JCPDS No.86-0928) and KMO (space group $C12/m1$, JCPDS No.29-1021) have monoclinic a structure [26-29]. All diffraction peaks in the XRD patterns belong to CSSO and KMO with no peaks from impurity phases detected. The intensity of KMO peaks increases as a function of its weight fraction.

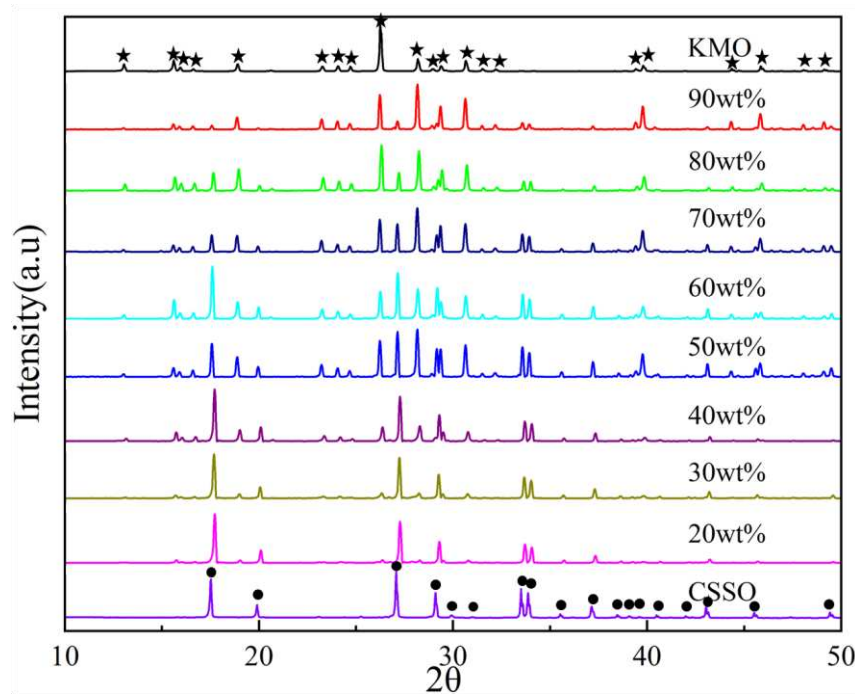


Figure 1. Room-temperature XRD patterns of (1-x)CSSO-xKMO composite ceramics fabricated by CSP, and CSSO powder synthesized by solid state reaction.

Fig. 2 displays the Raman spectra of cold-sintered (1-x)CSSO-xKMO composite ceramics at room temperature. According to group theory and irreducible representation, CSSO and KMO have 45 and 39 different vibration modes, respectively.

$$\Gamma_{\text{CSSO}} = 9A_g + 11A_u + 12B_g + 13B_u \quad (2)$$

$$\Gamma_{\text{KMO}} = 13A_g + 7A_u + 8B_g + 11B_u \quad (3)$$

The main Raman bands of CSSO are located at 135, 175, 295, 323, 363, 443, 510, 572 and 740 cm^{-1} , which are attributed to bending modes of the Ca-O bond (135, 175 and 295 cm^{-1}), $[\text{SiO}_4]^{4-}$ modes (443 and 510 cm^{-1}) and $[\text{SnO}_6]^-$ polyhedral modes (323, 363, 572 and 740 cm^{-1}) [33,34]. For KMO, Raman bands of 100 ~ 160 cm^{-1} are attributed to translations and vibrations modes of MoO_4 tetrahedra and translations of K^+ , bands at 310 ~ 370 cm^{-1} belong to bending modes of MoO_4 tetrahedra and modes at 820 ~ 890 cm^{-1} are assigned to stretching modes of MoO_4 tetrahedra [35,36]. As KMO concentration increases, the intensity of KMO Raman modes increases (as marked in orange frame) and all data except the end-members remains consistent with a two-phase mix with CSSO.

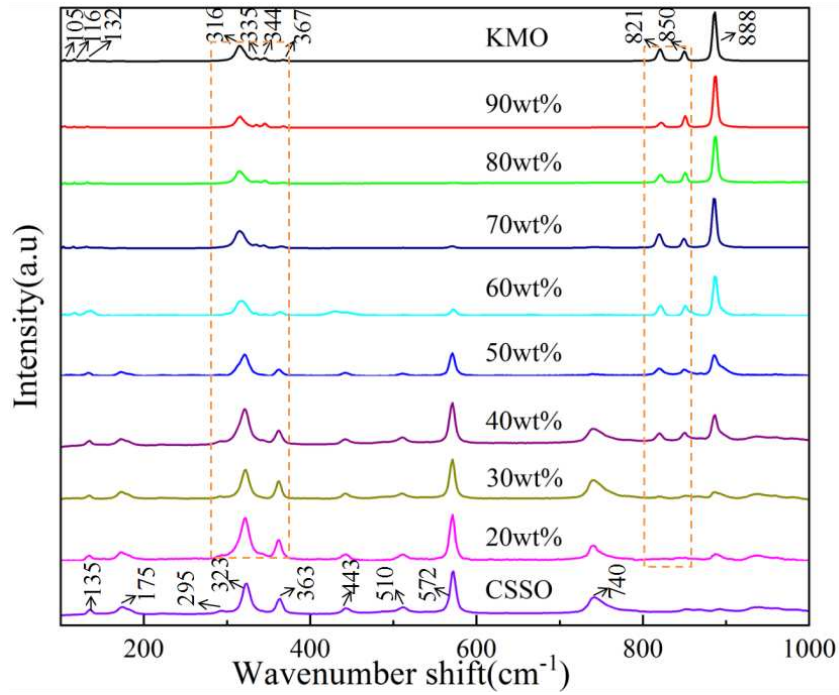


Figure 2. Raman spectra of (1-x)CSSO-xKMO composite ceramics.

Fig. 3(a) presents the SEM images of cold-sintered 70wt%CSSO-30wt%KMO composite ceramics. EDS spectra showed the elongated needle or sheet-shaped radial grains belong to KMO (indexed triangle shape), and the aggregated grains are CSSO (indexed circle shape). To verify the compatibility of cold-sintered (1-x)CSSO-xKMO composite ceramics with Ag electrodes, Ag powder was cold-sintered with 65wt%CSSO-35wt%KMO powder, Fig.3(b). The white area is the Ag electrode layer, which has a clean interface with

CSSO-KMO ceramic particles. EDS line scans suggest that there is no interact between Ag and CSSO-KMO composite, Fig. 4(c), indicating good chemical compatibility with Ag electrode.

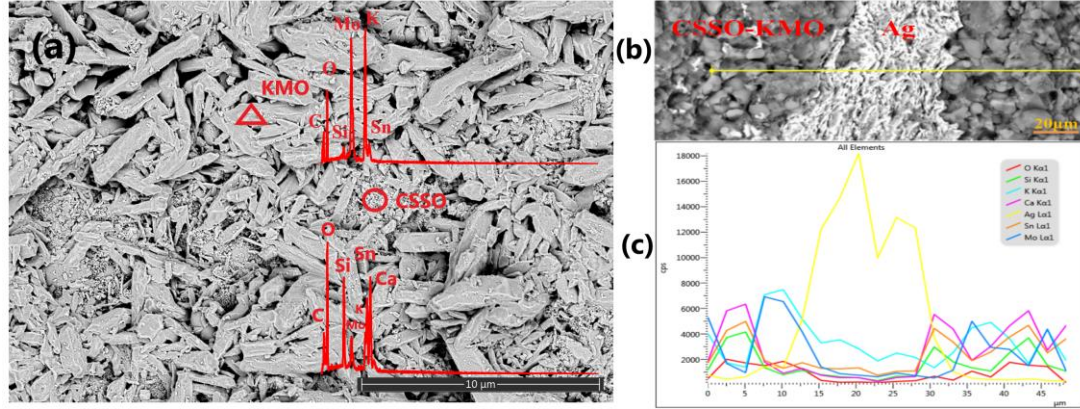


Figure 3. (a) SEM and EDS of etched polished surface of 70wt%CSSO-30wt%KMO sample (Triangle KMO, Circle CSSO); (b) SEM of the cross section of 65wt%CSSO-35wt%KMO sample co-sintered with silver, and (c) EDS elemental line.

The relative density (ρ_r) and microwave dielectric properties of (1-x)CSSO-xKMO composite ceramics as a function of KMO weight fraction are plotted in Fig. 4. ρ_r increases from 89% for 80wt%CSSO-20wt%KMO to near 100% for KMO. ϵ_r and τ_f decrease linearly as KMO weight fraction increases, while $Q \times f$ increases, Table 1. Near-zero τ_f (-0.5 ppm/°C) was obtained for 65wt%CSSO-35wt%KMO composites with $\epsilon_r \sim 9.168$ and $Q \times f \sim 6240$ GHz. According to the XRD, Raman and EDS, there are no chemical interactions between the two phases. Thus, the effective ϵ_r can be estimated by the Lichtenecker mixing law [37]:

$$\text{parallel mixing law, } \epsilon = V_1 \epsilon_1 + V_2 \epsilon_2 \quad (4)$$

$$\text{series mixing law, } 1/\epsilon = V_1 / \epsilon_1 + V_2 / \epsilon_2 \quad (5)$$

$$\text{logarithmic mixing law, } \epsilon = \epsilon_1^{V_1} \epsilon_2^{V_2} \text{ i.e., } \lg \epsilon = V_1 \lg \epsilon_1 + V_2 \lg \epsilon_2 \quad (6)$$

where ϵ_1 and ϵ_2 are the dielectric constants of phase 1 and phase 2, respectively. V_1 and V_2 ($V_1 + V_2 = 1$) are the volume fractions of phase 1 and phase 2 respectively. From Fig. 4(b), ϵ_r of (1-x)CSSO-xKMO composite ceramics is less than the calculated value of equation (4), larger than the calculated value of equation (5), and close to that obtained using equation (6), which shows that ϵ_r follows the logarithmic mixing law. τ_f may be predicted according to parallel mixing rules,

$$\tau_f = V_1\tau_{f1} + V_2\tau_{f2} \quad (7)$$

where τ_{f1} and τ_{f2} correspond to the τ_f of phase 1 and phase 2, respectively, as presented in Fig. 4(c).

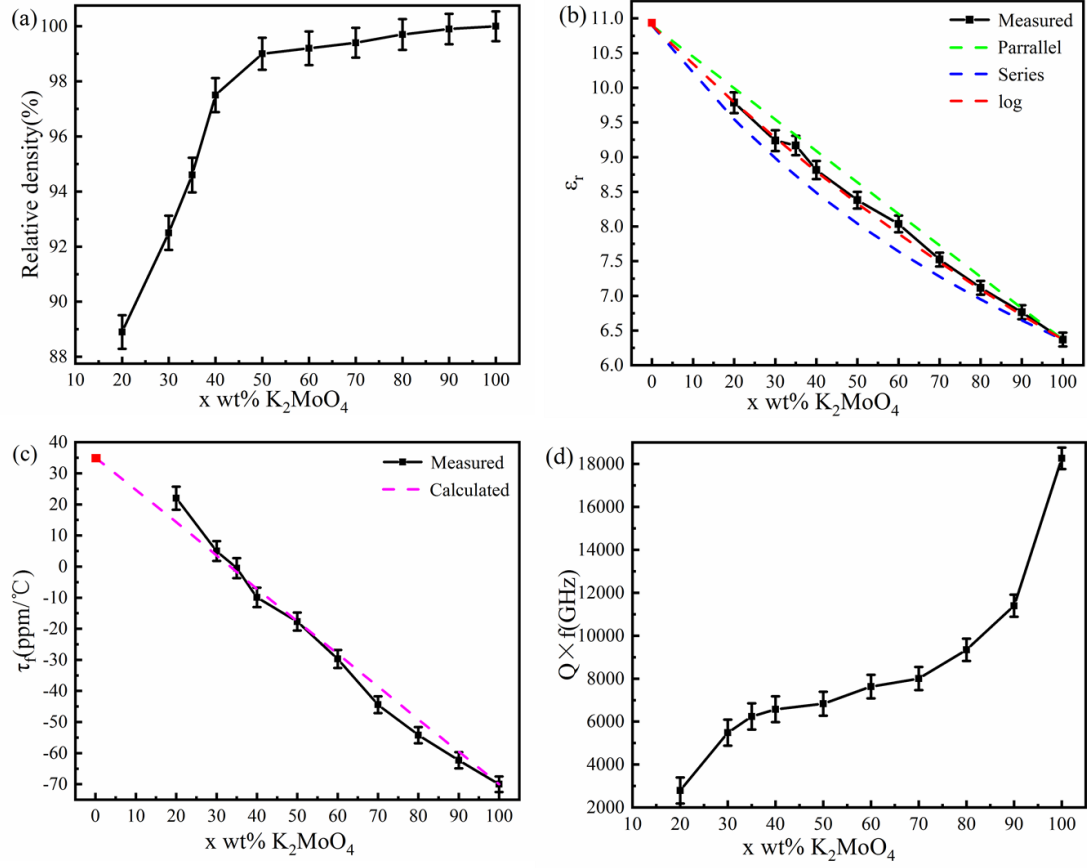


Figure 4. Microwave dielectric properties of (1-x)CSSO-xKMO composite ceramics as a wt fraction of KMO.

Table 1 Sintering temperature (ST), relative density (ρ_r), and microwave dielectric properties of (1-x)CSSO-xKMO ceramics.

Composition	ST(°C)	ρ_r (%)	ϵ_r	$Q \times f$ (GHz)	τ_f (ppm/°C)
CaSnSiO ₅	1450	95	10.9	43600	+35
20wt%K ₂ MoO ₄	180	89	9.78	2792	+22
30wt%K ₂ MoO ₄	180	93	9.24	5484	+5
35wt%K ₂ MoO ₄	180	95	9.17	6240	-0.5
40wt%K ₂ MoO ₄	180	98	8.82	6576	-9.9
50wt%K ₂ MoO ₄	180	99	8.38	6831	-18
60wt%K ₂ MoO ₄	180	99	8.04	7628	-30
70wt%K ₂ MoO ₄	180	99	7.52	8004	-44

80wt%K ₂ MoO ₄	180	100	7.12	9343	-54
90wt%K ₂ MoO ₄	180	100	6.76	11395	-62
K ₂ MoO ₄	150	100	6.37	18266	-70

Fig. 5 shows the temperature dependence of ϵ_r for 65wt%CSSO-35wt%KMO measured from 10 kHz to 1 MHz. ϵ_r is stable from room temperature to 250 °C, as shown in Fig. 7a, indicating no phase transition in this temperature range but decreases with increase in frequency as space charge contributions diminish (Fig. 5b). At room temperature, ϵ_r @ 1MHz is 10.8, close to the value at microwave frequencies in Table 1 (9.17).

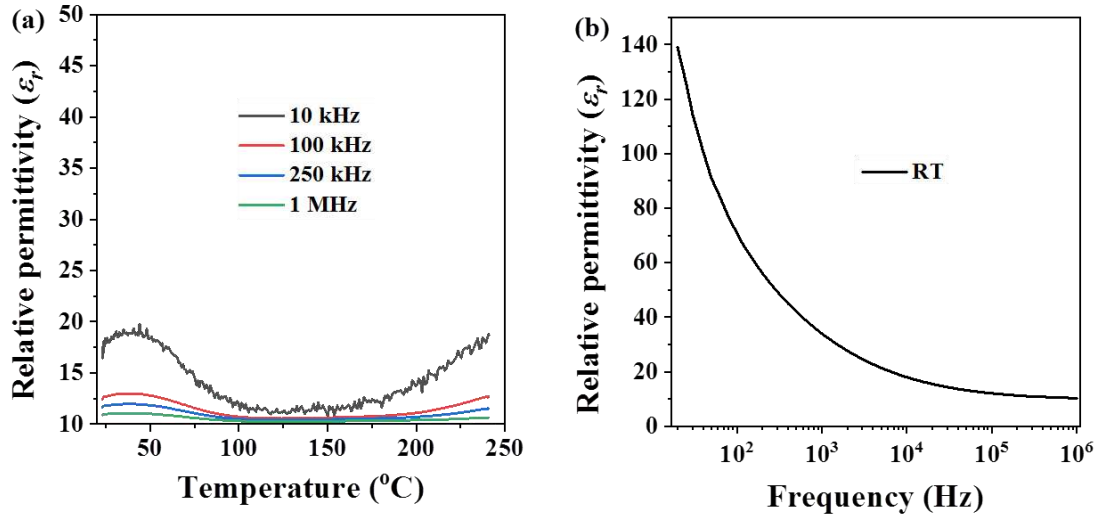


Figure 5. (a) Temperature dependence, (b) Frequency dependence of ϵ_r for 65wt%CSSO-35wt%KMO ceramic.

Room temperature EIS of 65wt%CSSO- 35wt%KMO is shown in Fig. 6. The complex impedance is divided into real part (Z') and imaginary part (Z'') and is expressed by the following formula.

$$Z = \frac{R}{1 + i\omega RC} = Z' - iZ'' \quad (8)$$

$$Z' = \frac{R}{1 + (\omega RC)^2} \quad (9)$$

$$Z'' = \frac{\omega R^2 C}{1 + (\omega RC)^2} \quad (10)$$

where ω is angular frequency. From Fig. 7(a), the observed non-perfect semicircle is equal to the sum of two smaller semicircles, corresponding to two Debye peaks in frequency

dependence of Z'' and M'' , Fig. 6(b), which indicates at least two electrical components. The extracted capacitances of these two components are $2.6 \times 10^{-12} \text{ F cm}^{-1}$ and $1.7 \times 10^{-12} \text{ F cm}^{-1}$ for component 1 and 2, respectively. The complex microstructure of the CSSO – KMO make attributing the components to a specific part of the microstructure difficult but the low temperature, low frequency response is consistent with the space-charge contribution observed in the LCR data, Figure 5, which decreases with increasing frequency and is absent in MW measurements, Figure 4.

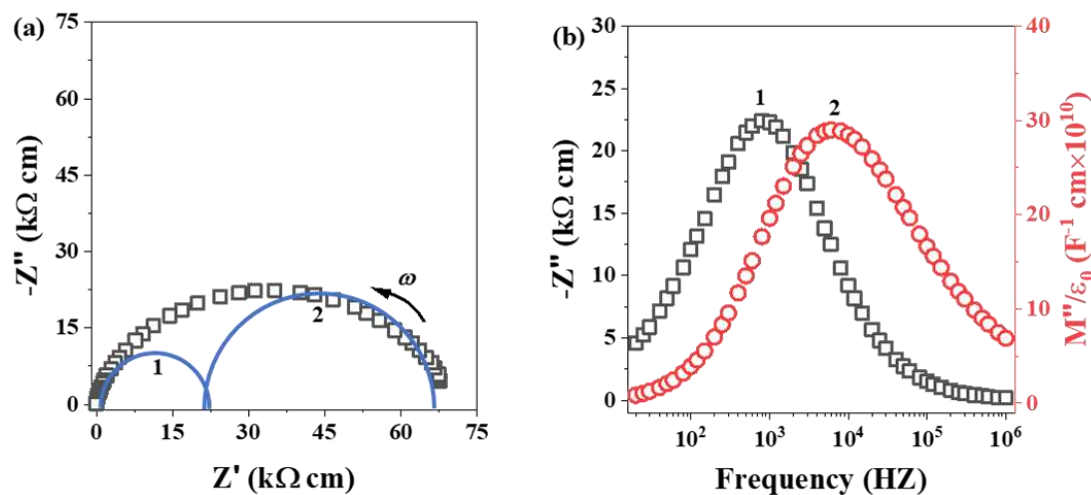


Figure 6. (a) Z^* plot, and (b) Frequency dependence of Z'' and M'' for 65wt%CSSO-35wt%KMO ceramic.

A 5G prototype microstrip patch antenna (MSPA) with a center operating frequency of 5.2 GHz was designed and fabricated using the 65wt%CSSO-35wt%KMO ceramic as a substrate. The radiation element (the patch) and the ground plane was made of adhesive copper tape. The patch had the dimensions of 11.71 mm x 11.55 mm and the feed point was 3.75 mm away from the patch edge. A semi-rigid coaxial cable (RG405) was used for providing the probe feeding. The thickness of 65wt%CSSO-35wt%KMO ceramic substrate was 1.45 mm. The fabricated MSPA is shown in the inset pattern of Fig. 7(a).

The measured and simulated S11 result is shown in Fig. 7(a), indicating a good agreement between the measurement and simulation. The MSPA also shows the good impedance match, with a -10 dB bandwidth of 144 MHz. The MSPA was measured in a Spherical Near-Field anechoic chamber. The measured radiation patterns at 5.2 GHz at two principle cut planes: magnetic plane (H-plane) and electric plane (E-plane) are shown in Fig.

7(b) and Fig. 7(d), respectively, compared with simulated results. Good agreement between simulation and measurement is observed. The measured antenna gain, directivity and total efficiency (including the impedance mismatch) are shown in Fig. 7(c). The MSPA has an antenna gain of 5.7 dBi and total efficiency of 88.4% at 5.2 GHz. The far-field performance suggests that 65wt%CSSO-35wt%KMO is a good candidate for antenna applications.

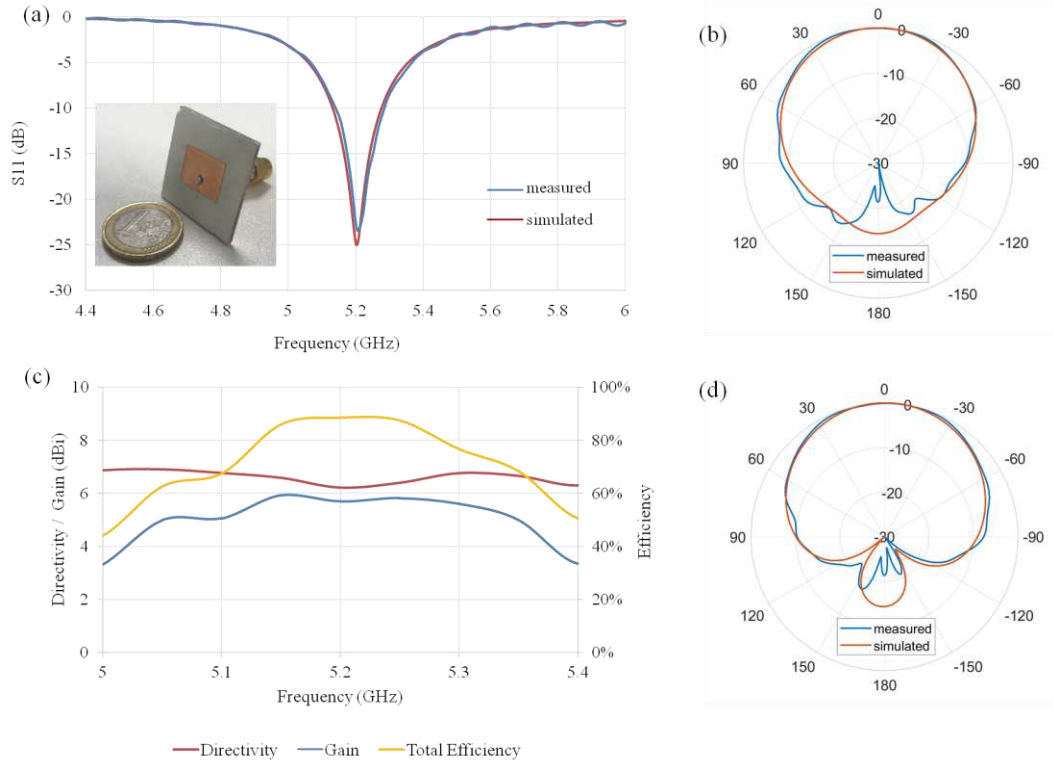


Figure 7. (a) Measured S11 result of MSPA, compared with the simulation; (c) Measured far-field performance of the MSPA; Radiation patterns of the MSPA at (b) H-plane, (d) E-plane.

CONCLUSIONS

(1-x)CSSO-xKMO microwave composite ceramics with 89%-100% relative density were successfully fabricated by CSP (180 °C, 60 min and 400 MPa). SEM showed that the composite ceramics had a dense microstructure. XRD, EDS and Raman spectra identified two discrete phases of CSSO and KMO, with no chemical interaction. With increasing weight fraction of KMO, ϵ_r and τ_f decreased, while $Q \times f$ increased. A near-zero $\tau_f \sim -0.5$ ppm/°C was obtained in 65wt%CSSO-35wt%KMO with $\epsilon_r \sim 9.17$ and $Q \times f \sim 6240$ GHz. ϵ_r was stable from room temperature to 250 °C but decreased in respect to frequency, consistent with a low

temperature, low frequency space charge contribution observed in EIS data. CSSO-KMO composite ceramics and Ag electrodes had good compatibility. A MSPA was designed and fabricated using cold sintered 65wt%CSSO-35wt%KMO as a substrate with a central operating frequency of 5.2 GHz. The antenna had an S11 of -10 dB with bandwidth of 144 MHz. The antenna gain of the MSPA was 5.7 dBi at 5.2 GHz, and the total efficiency was 88.4%.

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